

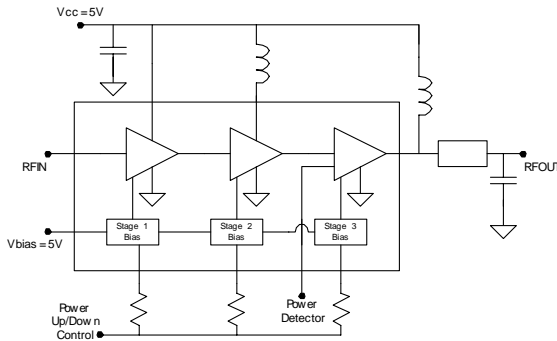


Product Description

Sirenza Microdevices' SZM-3166Z is a high linearity class AB Heterojunction Bipolar Transistor (HBT) amplifier housed in a low-cost surface-mountable plastic Q-FlexN multi-chip module package. This HBT amplifier is made with InGaP on GaAs device technology and fabricated with MOCVD for an ideal combination of low cost and high reliability.

This product is specifically designed for 802.16 customer premise equipment (CPE) terminals in the 3.3-3.6 GHz bands. It can run from a 3V to 5.2V supply. The external output match and bias adjustability allows load line optimization for other applications covering 3.5-3.8GHz. It features an output power detector, on/off power control and high RF overdrive robustness. A 20dB step attenuator feature can be utilized by switching the second stage Power up/down control. This product features a RoHS compliant and Green package with matte tin finish, designated by the 'Z' suffix.

Functional Block Diagram



Key Specifications

Symbol	Parameters: Test Conditions, 3.3-3.6GHz App circuit, $Z_0 = 50\Omega$, $V_{CC} = 5.2V$, $I_q = 800mA$, $T_{BP} = 30^\circ C$	Unit	Min.	Typ.	Max.
f_O	Frequency of Operation	MHz	3300		3600
P_{1dB}	Output Power at 1dB Compression – 3.5GHz	dBm		34.5	
S_{21}	Gain @ $P_{out} = 26dBm$ – 3.5GHz	dB	32	35	38
%	% EVM @ $P_{out} = 27dBm$, EVM 802.11g 54Mb/s - 3.5GHz	%		2.5	
IM3	Third Order Suppression ($P_{out}=23dBm$ per tone) - 3.5GHz	dBc		-42	-37
NF	Noise Figure at 3.5 GHz	dB		5	
IRL	Worst Case Input Return Loss 3.3-3.6GHz	dB	11	14	
ORL	Worst Case Output Return Loss 3.3-3.6GHz		6	9	
V_{CC}	Supply voltage range	V		5.2	
V_{det} Range	Output Voltage Range for $P_{out}=10dBm$ to 33dBm	V		0.9 to 2.2	
I_{cq}	Quiescent Current ($V_{CC} = 5.2V$)	mA	720	800	880
I_{VPC}	Power Up Control Current ($V_{pc}=5.2V$) ($I_{VPC1} + I_{VPC2} + I_{VPC3}$)	mA		5	
I_{leak}	V_{CC} Leakage Current ($V_{CC} = 5.2V$, $V_{pc} = 0V$)	mA			0.1
$R_{th, j-l}$	Thermal Resistance (junction - lead)	$^\circ C/W$		12	

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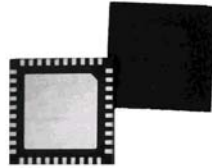
Phone: (800) SMI-MMIC

<http://www.sirenza.com>
EDS-105462 Rev C

Preliminary

SZM-3166Z

3.3-3.6GHz 2W Power Amplifier



6mm x 6mm QFN Package



Product Features

- $P_{1dB} = 35dBm$ @ 5.2V
- Three Stages of Gain: 35dB
- 802.11g 54Mb/s Class AB Performance
- $P_{out} = 27dBm$ @ 2.5% EVM, $V_{CC} 5.2V, 900mA$
- Active Bias with Adjustable Current
- On-chip Output Power Detector
- Low Thermal Resistance
- Power up/down control < $1\mu s$
- Attenuator Step 20dB @ $V_{pc2} = 0V$
- Class 1C ESD Rating

Applications

- 802.16 WiMAX Driver or Output Stage
- Fixed Wireless, WLL
- CPE Terminal Applications

Typical Performance 3.3-3.6GHz App Circuit (Vcc=5.2V, Icq=800mA, * 802.11g 54Mb/s 64QAM)

Parameter	Units	3.3GHz	3.4GHz	3.5GHz	3.6GHz	3.7GHz	3.8GHz
Gain @ Pout=26dBm	dB	35	35	35	35	33	31.5
P1dB	dBm	34	34.5	35	34.5	34	33
% EVM @ Pout = 27dBm*	%	2.7	2.5	2.5	2.6	3.1	4
Current @ Pout 2.5% EVM*	mA	930	930	920	893	910	885
Input Return Loss	dB	14	15	15.5	17	18.5	15.5
Output Return Loss	dB	9	10	10	9	8	7

Absolute Maximum Ratings

Parameters	Value	Unit
VC3 Collector Bias Current (I _{VC3})	1500	mA
VC2 Collector Bias Current (I _{VC2})	600	mA
VC1 Collector Bias Current (I _{VC1})	300	mA
**Device Voltage (V _D)	9.0	V
Power Dissipation	6	W
Operating Lead Temperature (T _L)	-40 to +85	°C
*Max RF output Power for 50 ohm continuous long term operation	30	dBm
Max RF Input Power for 50 ohm output load	29	dBm
Max RF Input Power for 10:1 VSWR output load	5	dBm
Max Storage Temperature	+150	°C
Operating Junction Temperature (T _J)	+150	°C
ESD Human Body Model	Class 1C	

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias conditions should also satisfy the following expression:

$$I_{cq} V_{cc} < (T_J - T_L) / R_{TH} \cdot J$$
 Note: I_{cq} in this equation is for the stage with the highest current

* With specified application circuit.

** No RF Drive



Caution: ESD Sensitive

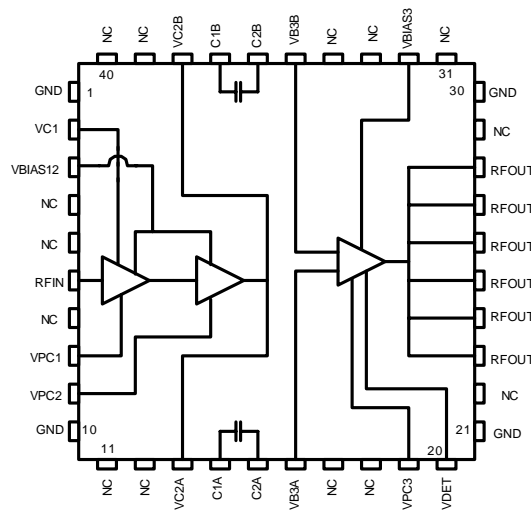
Appropriate precaution in handling, packaging and testing devices must be observed.



Pin Out Description

Pin #	Function	Description
5, 7, 11, 12, 17, 18, 22, 29, 31, 33, 34, 39, 40	NC	These are no connect (NC) pins and are not wired inside the package. It is recommended to connect them as shown in the application circuit to achieve the stated performance.
1, 10, 21, 30	GND	These pins are internally grounded inside the package to the backside ground paddle. It is recommended to also ground them external to the package to achieve the specified performance.
2	VC1	This is the collector of the first stage.
3	VBIAS12	This is the supply voltage for the active bias circuit of the 1st and 2nd stages.
4	NC	This pin is not connected inside the package, but it is recommended to connect it to GND to achieve the specified performance.
6	RFIN	This is the RF input pin. It is DC grounded inside the package. Do not apply DC voltage to this pin.
8	VPC1	Power up/down control pin for the 1st stage. An external series resistor is required for proper setting of bias levels depending on control voltage. The voltage on this pin should never exceed the voltage on pin 3 by more than 0.5V unless the supply current from pin 3 is limited < 10mA.
9	VPC2	Power up/down control pin for the 2nd stage. Power down VPC2<1V for step attenuator function enable. An external series resistor is required for proper setting of bias levels depending on control voltage. The voltage on this pin should never exceed the voltage on pin 3 by more than 0.5V unless the supply current from pin 3 is limited < 10mA.
13, 38	VC2A, VC2B	These two pins are connected internal to the package to the 2nd stage collector. To achieve specified performance, the layout of these pins should match the Recommended Land Pattern, pg. 9.
14, 15, 36, 37	C1A, C2A C1B, C2B	These pins have capacitors across them internal to the package as shown in the below schematic. They are used as tuning and RF coupling elements between the 2nd and 3rd stage.
16, 35	VB3A, VB3B	These are the connections to the base of the 3rd stage output device. To achieve specified performance, the layout of these pins should match the Recommended Land Pattern, pg. 9.
19	VPC3	Power up/down control pin for the 3rd stage. An external series resistor is required for proper setting of bias levels depending on control voltage. The voltage on this pin should never exceed the voltage on pin 32 by more than 0.5V unless the supply current from pin 33 is limited < 10mA.
20	VDET	This is the output port for the power detector. It samples the power at the input of the 3rd stage.
23-28	RFOUT	These are the RF output pins and DC connections to the 3rd stage collector.
32	VBIAS3	This is the supply voltage for the active bias circuit of the 3rd stage.

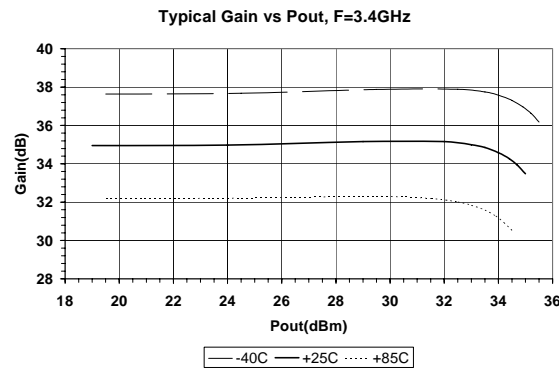
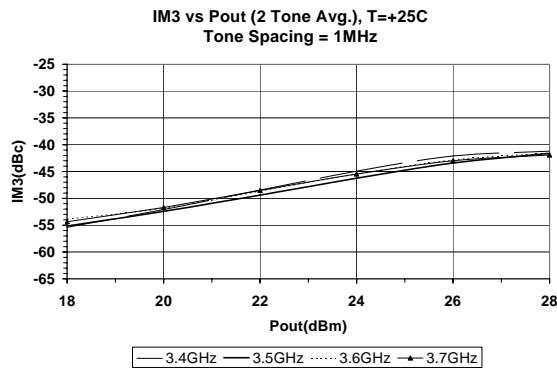
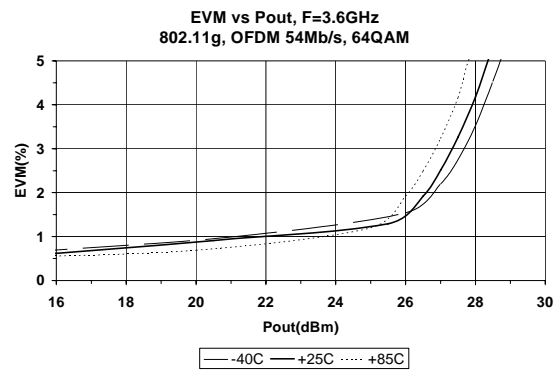
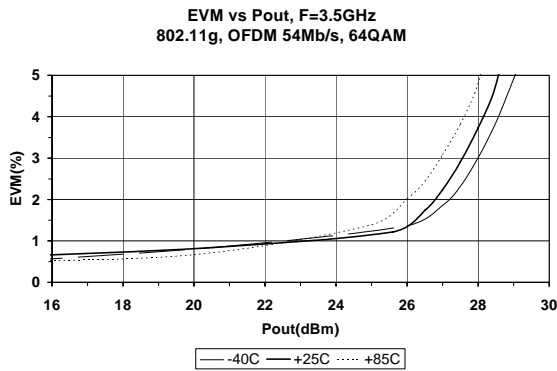
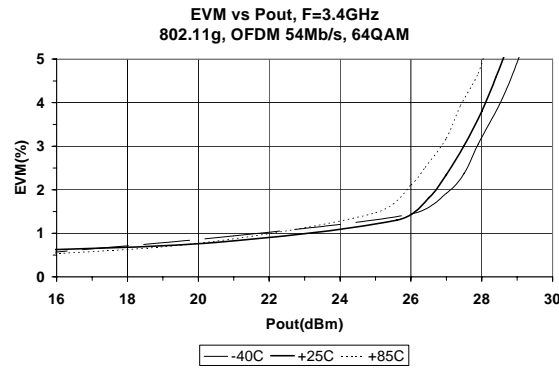
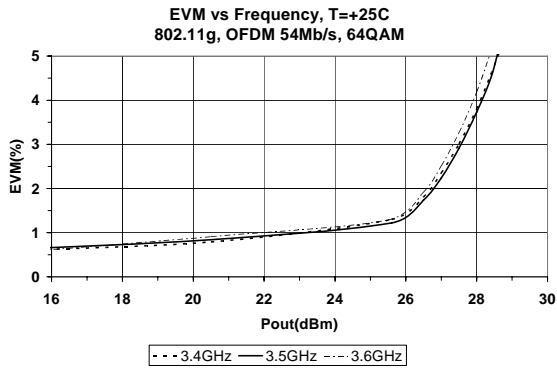
Simplified Device Schematic





Preliminary
SZM-3166Z 3.3-3.6GHz 2W Power Amp

Measured 3.3 - 3.6 GHz Application Circuit Data ($V_{CC} = V_{PC} = 5.2V, I_q = 800mA, T = 25C$)

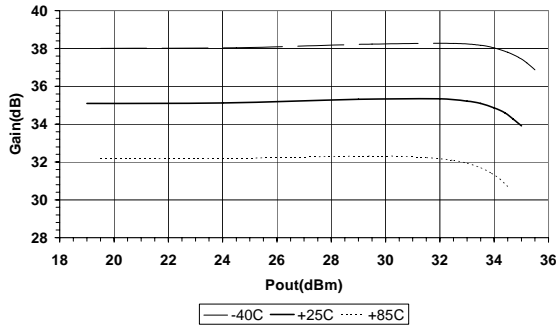




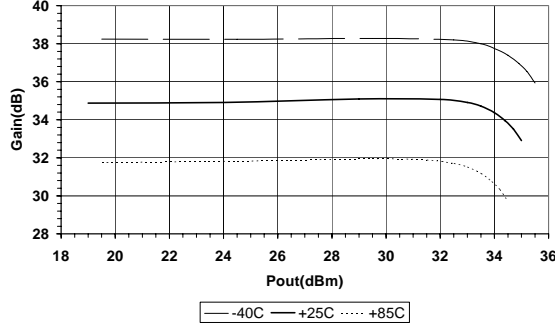
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SZM-3166Z 3.3-3.6GHz 2W Power Amp

Measured 3.3 - 3.6 GHz Application Circuit Data ($V_{CC} = V_{PC} = 5.2V$, $I_q = 800mA$, $T = 25C$)

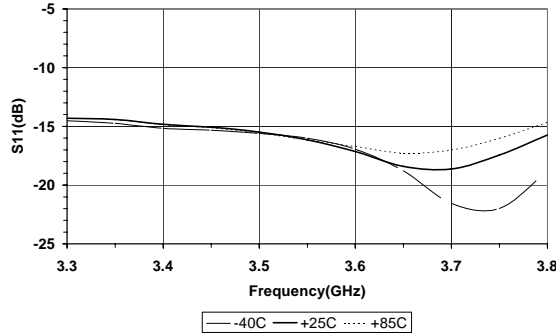
Typical Gain vs Pout, F=3.5GHz



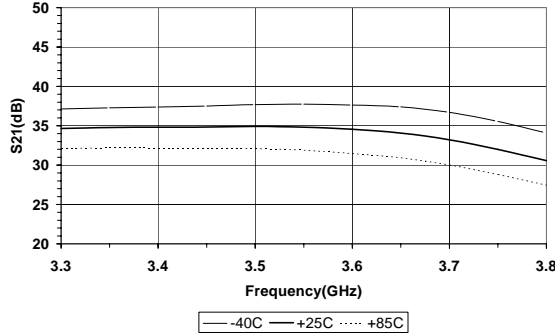
Typical Gain vs Pout, F=3.6GHz



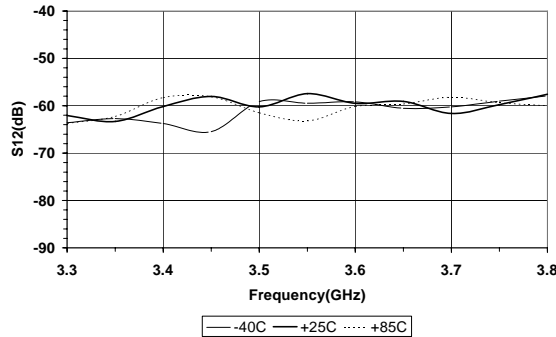
Narrowband S11 - Input Return Loss



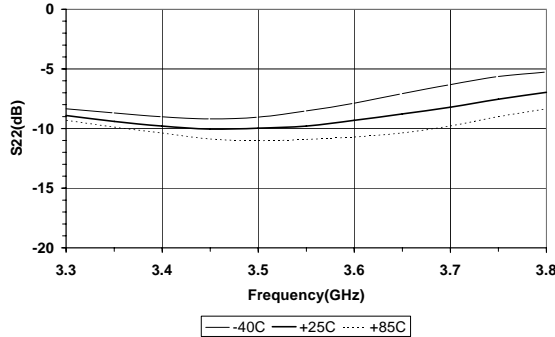
Narrowband S21 - Forward Gain



Narrowband S12 - Reverse Isolation



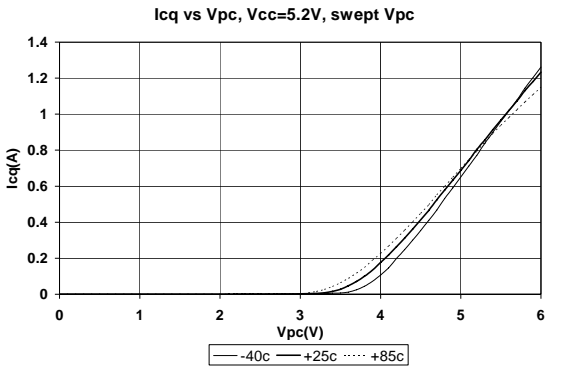
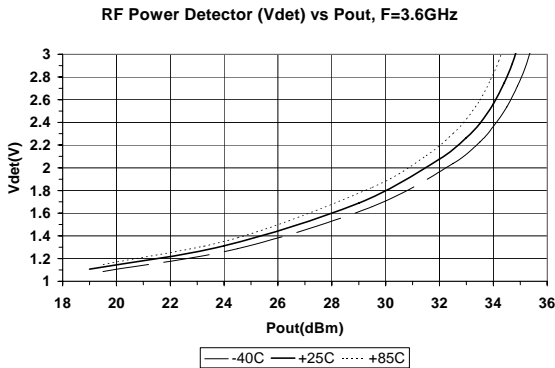
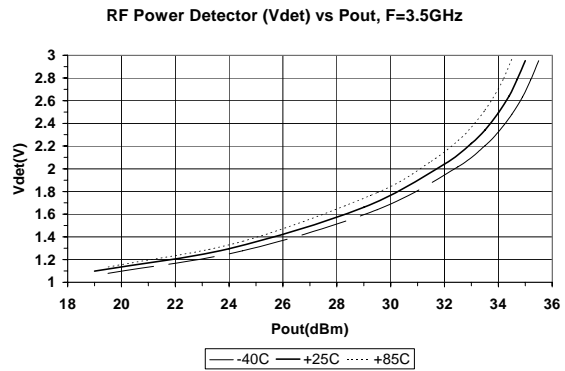
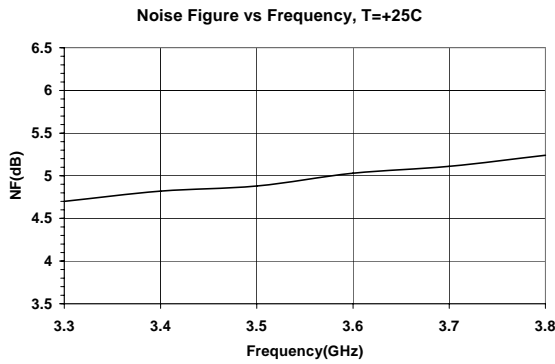
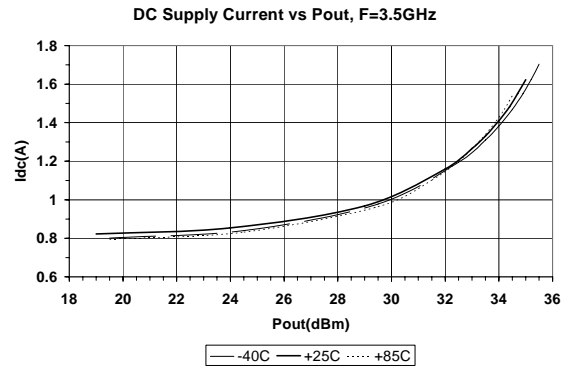
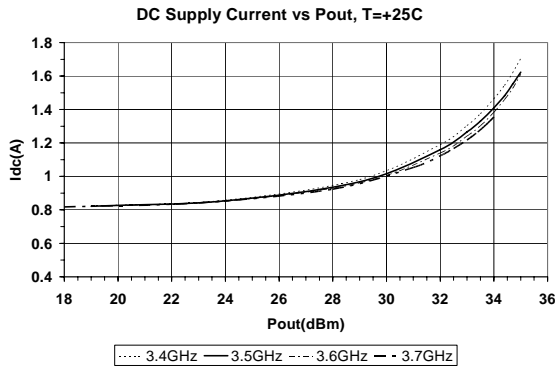
Narrowband S22 - Output Return Loss





Preliminary
SZM-3166Z 3.3-3.6GHz 2W Power Amp

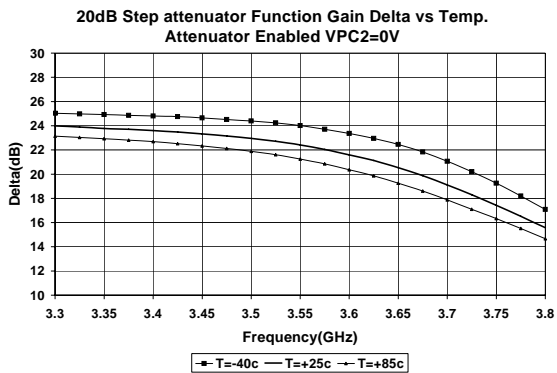
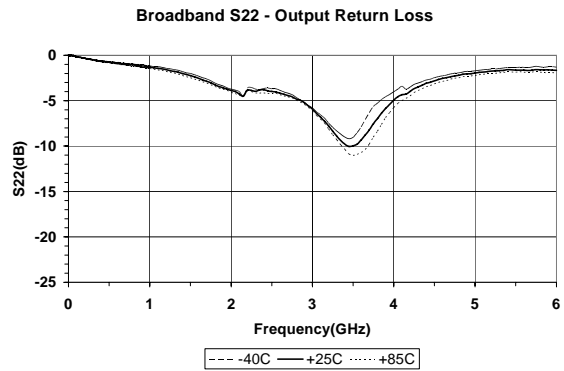
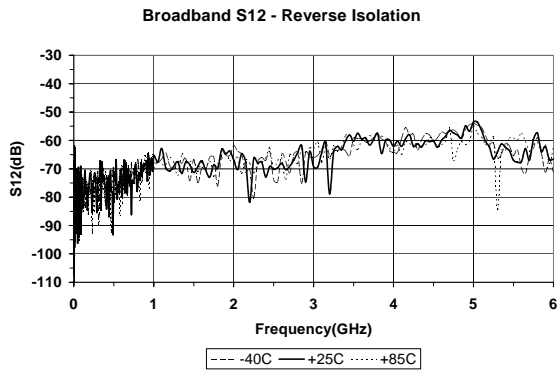
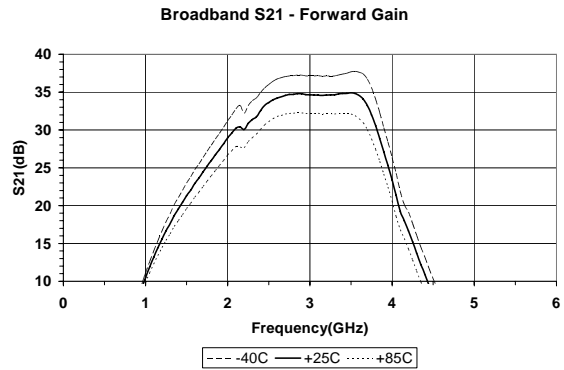
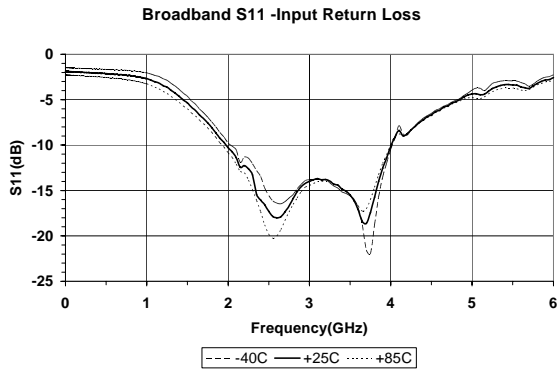
Measured 3.3 - 3.6 GHz Application Circuit Data ($V_{CC} = V_{PC} = 5.2V, I_q = 800mA, T=25C$)



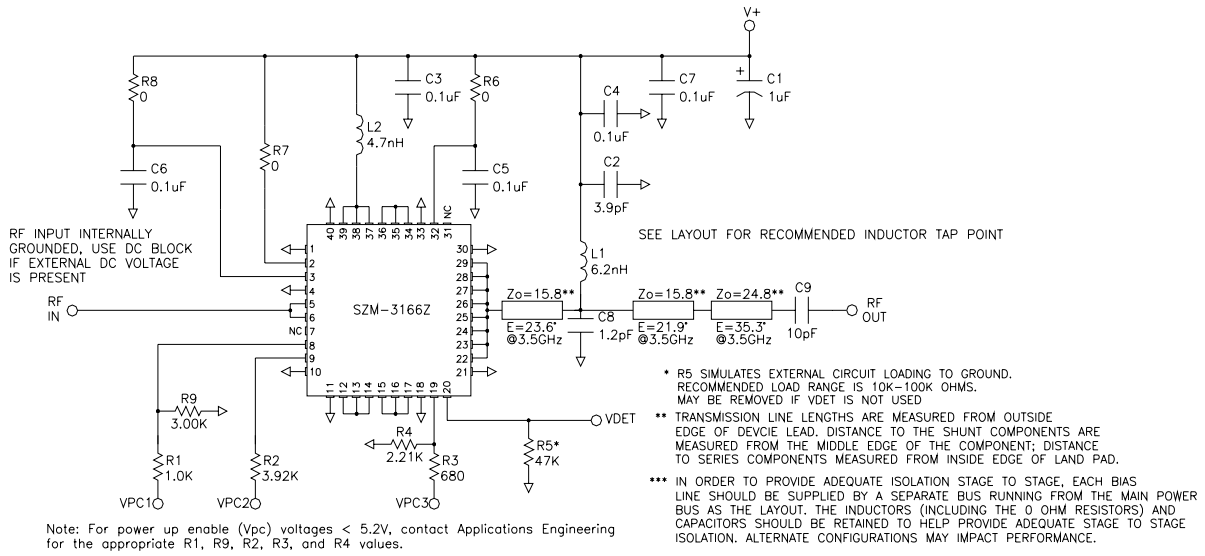


Preliminary
SZM-3166Z 3.3-3.6GHz 2W Power Amp

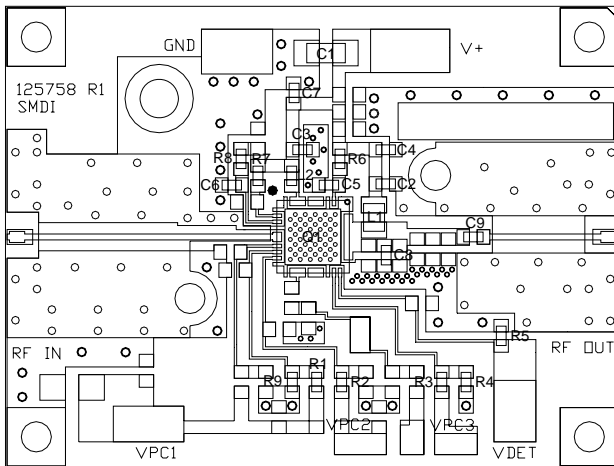
Measured 3.3 - 3.6 GHz Application Circuit Data ($V_{CC} = V_{PC} = 5.2V$, $I_q = 800mA$, $T=25C$)



3.3-3.6 GHz Evaluation Board Schematic For Vcc = Vpc =5.2V



3.3-3.6 GHz Evaluation Board Layout For Vcc = Vpc = 5.2V
 Board material GETEK, 10mil thick, Dk=3.9, 2 oz. copper



DESG	DESCRIPTION	NOTES
Q1	SZM-3166Z	6x6mm 0FN
R1	1.0K OHM, 0603 1%	0402 may be used
R2	3.92K OHM, 0603 1%	"
R3	680 OHM, 0603 1%	"
R4	2.21K OHM, 0603 1%	"
R5	47K OHM, 0603	"
R6,7,8	0 OHM, 0603	"
R9	3K OHM, 0603 1%	"
C1	1uF 16V MLCC CAP	Tantalum ok for EVM performance Use MLCC type for best IM3 levels
C2	3.9pF CAP, 0603	NPO ROHM MCH185A3R9DK or equiv.
C3,4,5,6,7	0.1uF CAP, 0603	NPO 0402 ok ATC 600S1R5CW250 or equiv.
C8	1.2pF CAP, 0603	NPO, low ESR ATC 600S1R5CW250 or equiv.
C9	10pF CAP, 0603	NPO, low ESR ATC 600S100JW250 or equiv.
L1	6.2nH IND 0805	Coilcraft 0805HQ - 6N2XJBB
L2	4.7nH IND, 0603	TOKO 0603 - LL1608FH4N7J



Preliminary

SZM-3166Z 3.3-3.6GHz 2W Power Amp

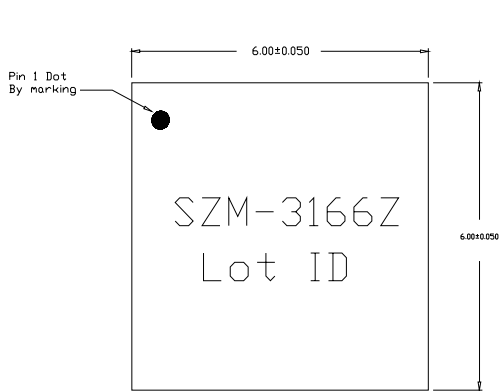
Part Symbolization

The part will be symbolized with "SZM-3166Z" to designate it as a RoHS green compliant product. Marking designator will be on the top surface of the package.

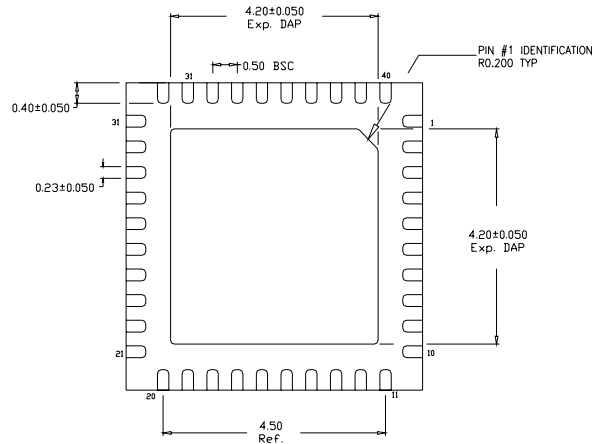
Part Number Ordering Information

Part Number	Description	Reel Size	Reel Quantity
SZM-3166Z	Lead Free, RoHS compliant	7"	1000
SZM-3166Z-EVB1	3.3-3.6GHz Evaluation Board	N/A	N/A

Package Outline Drawing (dimensions in mm):



TOP VIEW

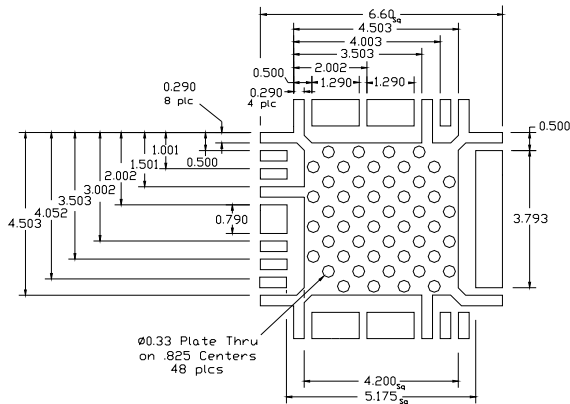


BOTTOM VIEW



SIDE VIEW

Recommended Metal Land Pattern (dimensions in mm[in]):



Recommended PCB Soldermask for Land Pattern (dimensions in mm[in]):

